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SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	Submission to correct an error in a cover sheet previously recorded at Reel 015831, Frame 0914. The correction is to the spelling of the assignee's name.

CONVEYING PARTY DATA

Name	Execution Date
Ecole Polytechnique Federale de Lausanne	12/11/2008

RECEIVING PARTY DATA

Name:	Innovative Silicon ISi SA
Street Address:	PSE-Batiment B
City:	Lausanne
State/Country:	SWITZERLAND
Postal Code:	CH-1015

PROPERTY NUMBERS Total: 1

Property Type	Number
Application Number:	10487162

CORRESPONDENCE DATA

Fax Number: (202)261-2168

Correspondence will be sent via US Mail when the fax attempt is unsuccessful.

Email: neils@swpatentlaw.com

Correspondent Name: Neil A. Steinberg
Address Line 1: 2300 M Street, N.W.

Address Line 2: Suite 800

Address Line 4: Washington, DISTRICT OF COLUMBIA 20037

ATTORNEY DOCKET NUMBER:	211.002-US EPFL
NAME OF SUBMITTER:	Neil A. Steinberg

Total Attachments: 17

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October ___, 2008

Mr. Gabriel Clerc
Service des relations industrielles
Ecole Polytechnique Fédérale de Lausanne
CH – 1015
Lausanne, Switzerland

Professor Declercq
Ecole Polytechnique Fédérale de Lausanne
STI-LEG
CH – 1015
Lausanne, Switzerland

Dear Messrs. Clerc and Declercq:

I am writing in order to correct typographical errors that appear in certain places in the following agreements (collectively, the "Agreements"):

- 1) Agreement by and among Ecole Polytechnique Fédérale de Lausanne ("EPFL"), Innovative Silicon ISi SA, and the Founders (Pierre Fazan, Serguei Okhonin, André Borschberg, and Luc Bauer) dated on or about December 6, 2002, as amended December 11, 2003, and
- 2) Agreement by and among EPFL, Innovative Silicon, Inc., and Innovative Silicon ISi SA dated on or about April 29, 2005.

Specifically, the Agreements sometimes refer to Innovative Silicon's Swiss corporate entity as "Innovative Silicon SA" instead of the formal legal name, which is "Innovative Silicon ISi SA". Notably, in other places, including the signature pages, the formal legal name for the Swiss entity is used. In addition, the Agreements refer to Innovative Silicon's U.S. entity (a Delaware corporation) as "Innovative Silicon Inc." instead of the formal legal name, which is "Innovative Silicon, Inc."

We hereby confirm that Innovative Silicon, Inc., and Innovative Silicon ISi SA were the initial parties to the Agreements, and, of course, remain parties to the Agreements.

Innovative Silicon, Inc. | 4800 Great America Pkwy, Ste. 500, Santa Clara, CA 95054, USA | www.z-ram.com



Please indicate EPFL's acknowledgement and agreement, by signing in the space provided below, that all references in the Agreements to Innovative Silicon's Swiss corporate entity were intended and hereby are corrected to read and shall read "Innovative Silicon ISi SA" and that all references to Innovative Silicon's U.S. corporate entity were intended and hereby are corrected to read and shall read "Innovative Silicon, Inc."

Thank you for your assistance with this matter.

Sincerely,

Mark-Eric Jones President & CEO

Innovative Silicon, Inc. and Innovative Silicon ISi SA

Acknowledged and Agreed on behalf of Ecole Polytechnique Fédérale de Lausanne

Name: CLERC GABRIEL
Title: Head of SRI-EPFL
Date: Dec. 11th. 2008

SERVICE DES RELATIONS INDUSTRIELLES

Innovative Silicon, Inc. | 4800 Great America Pkwy, Ste. 500, Santa Clara, CA 95054, USA | www.z-ram.com

U.S. DEPARTMENT OF COMMERCE United States Patent and Trademark Office OMB No. 0651-0027 (exp. 6/30/2005) RECORDATION FORM COVER SHEET **PATENTS ONLY** To the Director of the U.S. Patent and Trademark Office: Please record the attached documents or the new address(es) below. 2. Name and address of receiving party(ies) 1. Name of conveying party(ies)/Execution Date(s): Name: Innovative Silicon S.A. Ecole Polytechnique Fédérale de Lausanne Internal Address: _ Execution Date(s) December 6, 2002 Street Address: PSE - Batiment B Yes V No Additional name(s) of conveying party(ies) attached? 3. Nature of conveyance:

s. Nature of Conveyance.		
✓ Assignment	City: Lausanne	
Security Agreement Change of Name	State:	
Government Interest Assignment Executive Order 9424, Confirmatory License	Country: Switzerland Zip: CH-1015	
Other	Additional name(s) & address(es) attached? Yes Vo	
A. Patent Application No.(s) 10/487,162	document is being filed together with a new application. B. Patent No.(s)	
Additional numbers at	tached? Yes VNo	
5. Name and address to whom correspondence concerning document should be mailed:	6. Total number of applications and patents involved:	
Name:Neil A. Steinberg	7. Total fee (37 CFR 1.21(h) & 3.41) \$ 40.00	
Internal Address:	Authorized to be charged by credit card Authorized to be charged to deposit account	
Street Address: 2665 Marine Way, Suite 1150	Enclosed None required (government interest not affecting title)	
City: Mountain View	8. Payment Information a. Credit Card Last 4 Numbers	
State: CA Zip: 94043	Expiration Date	
Phone Number: 650-968-8079	b. Deposit Account Number 50-0763 Authorized User Name Neil A. Steinberg	
Fax Number: 650-968-8102		
Email Address: neils@swpatentlaw.com		
9. Signature:	March 3, 2005	
J Signature	Date	

Documents to be recorded (including cover sheet) should be faxed to (703) 306-5995, or mailed to: Mail Stop Assignment Recordation Services, Director of the USPTO, P.O.Box 1450, Alexandria, V.A. 22313-1450

Neil A. Steinberg

Name of Person Signing

Total number of pages including cover

sheet, attachments, and documents:

14

AGREEMENT

18/11/03 20:21 FAX 41 216938990

between

Ecole Polytechnique Fédérale de Lausanne,

CH-1015 Lausanne, Switzerland, represented by Prof. Declercq, Head of Electronics Laboratory (hereafter referred to as "EPFL")

on the one part,

and

Innovative Silicon SA

PSE-B

CH-1015 Lausanne, Switzerland represented by André Borschberg and Pierre Fazan

(hereafter referred to as "ISi")

on the second part,

and

Pierre Fazan

Av. Du Carroz 1 CH-1110 Morges

and

Serguei Okhonin

Jolimont 2 CH-1005 Lausanne

and

André Borschberg

9 route de Lausanne CH-1260 Nyon

and

Luc Bauer 6 ch. Des Clos

cn. Des Clos 2073Enges

(hereafter collectively referred to as "the Founders")

on the third part.

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Preamble

Researchers from the Electronics Laboratory of EPFL and Pierre Fazan Innovative Silicon Solutions at Morges, Switzerland (the latter hereafter referred to as "ISS"), have generated and developed a concept of semiconductor devices exploiting the floating body effect.

In an agreement dated September 11, 2001, EPFL and (SS agreed that patent applications to be filed on this concept shall be jointly owned by ISS and EPFL, namely in a proportion of two thirds for ISS and one third for EPFL.

EPFL and ISS have filed an initial patent application on the above mentioned concept.

On May 22, 2002, the Founders have set up 1Si.

By a separate agreement dated September 12, 2002, ISS has assigned to ISi all its rights to the initial patent application.

EPFL and ISi have filed other patent applications on the concept and its applications.

With the aim to allow further development of the concept and its use for the benefit of the public, EPFL is willing to irrevocably fully assign to ISi its co-ownership rights on the said patent applications and to grant a non-exclusive license on certain software and layouts, under the terms and conditions set forth hereafter.

ARTICLE 1 - DEFINITIONS

- Patents

"Patents" shall mean the patent applications filed or to be filed, which are listed in Exhibit 1 hereto, as well as all patents issued from the said patent applications. The text of the 3 patent applications to be filed is appended in Exhibit 1.

Technology

"Technology" shall mean the technologies covered by one or more Patents.

"Field" shall mean semi-conductor memories excluding CMOS imagers and sensors.

- Licensed Items

"Licensed Items" shall mean the software and the layouts defined in Exhibit 2 hereto.

ARTICLE 2 - ASSIGNMENT - LICENSE

EPFL hereby irrevocably sells, assigns and transfers to ISi, which accepts, any and all its co-ownership rights to the Patents. As a result thereof, ISi shall have sole and full ownership to the Patents, in particular the exclusive right to use and exploit the Technology and the Patents in all fields of applications, including the right to

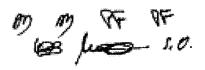
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manufacture, have manufactured, sell and license products and/or processes based on the Technology and/or the Patents. EPFL agrees, upon ISi request, to execute any documents necessary for effecting the sale, assignment and transfer of the Patents to ISi contemplated hereunder.

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PATENT

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This Agreement is executed in three originals and duly signed by the parties hereto, as printed below:

Ecole Polytechnique Fédérale de Lausanne

Innovative Silicon ISi S.A.

Place and date: Lausance, Dec 6,2002 Place and date: Lausinne, Dec. 64. 2002

(signature)

Prof. Declercq, Head of Electronics Laboratory

(signatures)

A. Borschberg, Director

P. Fazan, Director

Pierre Fazan

Place and date: Jawains Rc. 6, 2002 Signature: Varion

Serguei Okhonin

Place and date: bausanue, Dec 6, 2002

André Borschberg

Place and date: Louis one Dec 64 2002

Luc Bauer

Signature:

Exhibit 1:

Exhibit 2:

Exhibit 3:

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Exhibit 1: List of Patent Applications filed or to be filed

a) List of Patent Applications Filed:

Referenc	Reference Law firm	Title	Filing Date	Filing Number	Inventors
Case 1	Gresset	Dispositif semi-conducteur, notamment mémoire DRAM	18.06.01	EP 01810587.4	Pierre Fazan Serguei Okhonin
Case 2	Gresset	Procédé de commande d'un dispositif semi-conducteur	28.03.02	EP 02405247.4	Pierre Fazan Serguei Okhonin
Case 3	Gresset	Dispositif de rafraîchissement d'une mémoire	18.04.02	EP 02405314.2	Pierre Fazan Serguei Okhonin
Case 4	Gresset	Procédé pour créer une charge électrique dans le corps d'un composant semi-conducteur	18.04.02	EP 02405315.9	Pierre Fazan Serguel Okhonin
Case 5	Gresset	Dispositif semi-conducteur porteur d'une charge électrique	18.04.02	EP 02405316.7	Pierre Fazan Serguei Okhonin
PCT	UDF	Semiconductor Device	05.06.02	PCT/EP02/05495	Pierre Fazan Serguel Oktronin
Саѕе 3	d D	Data storage device and refreshing method for use with such device	29.05.02	EP 02077116.8	Pierre Fazan Serguel Okhonin
Case 5	j O	Serriconductor device	27.08.02	EP02078585.3	Pierre Fazan Serguei Okhonin

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Maher Kayal Marc Pastre Maria Blagojevich Michel Declercq	Lionel Portmann	Richard Ferrant
N.A.	N.A.	N.A.
N. A.	N.A.	N.A.
Method and apparatus for controlling semiconductor memory device	Method and apparatus for generating reference current in semiconductor memory device	Sense & Compare amplifier
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Case 6 UDL	Case 7 UDL	Case 10 UDL

Note: The PCT application is the result of a PCT filing combining cases 1,2,4,8, and 9.

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Exhibit 2:

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Exhibit 3:

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